Physics II (PH 102) Electromagnetism (Lecture 11)

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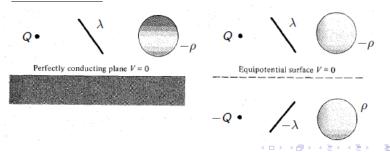
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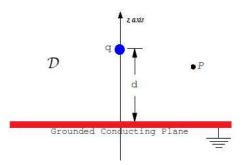
- 1. Central idea: Map the original hard problem to another easier problem, but satisfying the same boundary conditions. Then Uniqueness Theorem guarantees the correctness of the solution.
- 2. Use Fact: All conducting surfaces are represented by equipotentials.
- 3. Strategy: All Real charge configurations and conducting surfaces are replaced by the same Real charges, equipotential surfaces and some additional **fictitious** charges or charge distributions in the conducting region, called *Image Charges*.



The Classic Image Problem

Example

Suppose a point charge q is held at a distance d above a infinite grounded conducting plane. What is the Electrostatic Potential at point P in the non-conducting region D above the conducting plane?

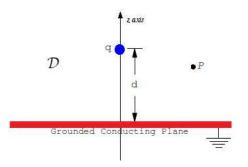


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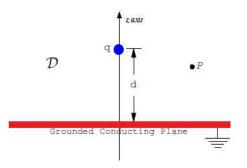
The Electrostatic Potential V at point P ≡ (x, y, z) will be due to point charge q and the induced surface charges.

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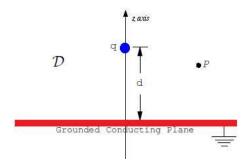
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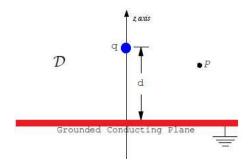


- ▶ The Electrostatic Potential V at point $P \equiv (x, y, z)$ will be due to point charge q and the induced surface charges.
- Problem is, we do not know $\sigma(x, y)$ a priori ! How to determine V(x, y, z) without directly knowing $\sigma(x, y)$ on the conducting plane?

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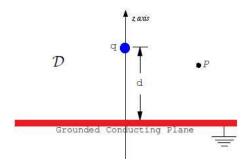
Set up a co-ordinate system with *xy*-plane as the given infinite conducting plane and *q* lies on the *z*-axis:



Set up a co-ordinate system with xy-plane as the given infinite conducting plane and q lies on the z-axis:

Sol. Domain:
$$\mathcal{D} = \{\mathbf{r} \mid z > 0\}$$

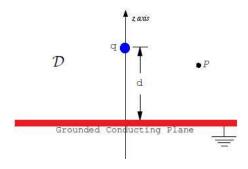
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 - $S = {xy-plane} \cup S_{\infty+}$

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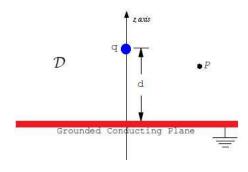
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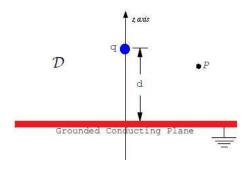
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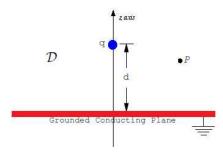
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Boundary Condition on V in the original problem:

$$V(\mathbf{S}) = 0, \quad \forall \mathbf{S} \in S$$

Real System is mapped on to the Fictitious System satisfying the same b.c.

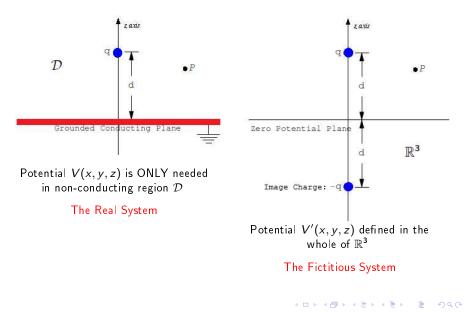
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Potential V(x, y, z) is ONLY needed in non-conducting region \mathcal{D}

The Real System

Real System is mapped on to the Fictitious System satisfying the same b.c.



Consider the Fictitious System:

• Charge distribution:
$$\rho'(\mathbf{r}) = q\delta^3(\mathbf{r} - \mathbf{r}_0) + (-q)\delta^3(\mathbf{r} + \mathbf{r}_0); \quad \mathbf{r}_0 = (0, 0, d)$$

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▶ Electrostatic Potential in all of $\mathbb{R}^3 \rightarrow \text{Trivial}$ to calculate!

$$V'(x, y, z) = \frac{1}{4\pi\epsilon_0} \left[\frac{q}{\sqrt{x^2 + y^2 + (z - d)^2}} + \frac{(-q)}{\sqrt{x^2 + y^2 + (z + d)^2}} \right]$$

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• $V'(\mathbf{r})$ satisfies **Poisson's Equation** $\forall \mathbf{r} \in \mathbb{R}^3$:

$$\nabla^2 V'(\mathbf{r}) = \frac{1}{\epsilon_0} \rho'(\mathbf{r})$$

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1. Real charge configuration in the common region ${\cal D}$ is identical:

$$\rho'(\mathbf{r})|_{\mathcal{D}} \xrightarrow{z>0} \rho(\mathbf{r})$$

2. Boundary conditions in the common region \mathcal{D} are identical:

$$\nabla^2 V' = \frac{1}{\epsilon_0} \rho' \quad \text{over } \mathbb{R}^3 \quad \xrightarrow{z>0} \quad \nabla^2 V = \frac{1}{\epsilon_0} \rho \quad \text{over } \mathcal{D} \subset \mathbb{R}^3,$$
$$V' = 0 \quad \text{on } S' \quad \xrightarrow{z>0} \quad V = 0 \quad \text{on } S \subset S'$$

Infinite grounded conducting plane: Potential

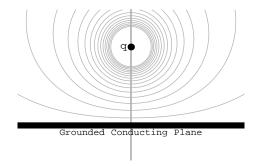
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Electrostatic Potential in \mathcal{D} : $V(x, y, z) = V'(x, y, z \ge 0)$, i.e.,

$$V(x, y, z) = \frac{q}{4\pi\epsilon_0} \left[\frac{1}{\sqrt{x^2 + y^2 + (z - d)^2}} - \frac{1}{\sqrt{x^2 + y^2 + (z + d)^2}} \right]$$

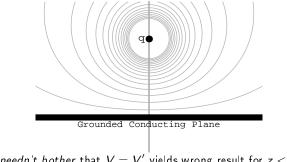


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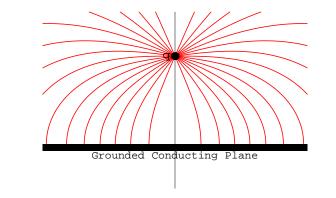


Note: We needn't bother that V = V' yields wrong result for z < 0!

Infinite grounded conducting plane: Electric Field

Electrostatic Field in
$$\mathcal{D}$$
: $\mathbf{E}(x, y, z) = \mathbf{E}'(x, y, z \ge 0) = -\nabla V(x, y, z)$, i.e.,

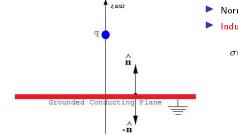
$$\mathbf{E}(x, y, z) = \frac{q}{4\pi\epsilon_0} \left[\frac{x\hat{\mathbf{i}} + y\hat{\mathbf{j}} + (z - d)\hat{\mathbf{k}}}{(x^2 + y^2 + (z - d)^2)^{3/2}} - \frac{x\hat{\mathbf{i}} + y\hat{\mathbf{j}} + (z + d)\hat{\mathbf{k}}}{(x^2 + y^2 + (z + d)^2)^{3/2}} \right]$$



Note: Again we needn't bother that $\mathbf{E}(\mathbf{r}) = \mathbf{E}'(\mathbf{r})$ yields wrong result for z < 0!

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Infinite grounded conducting plane: Surface Charge Density

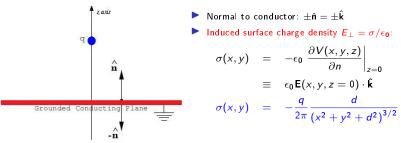


Normal to conductor:
$$\pm \hat{\mathbf{n}} = \pm \hat{\mathbf{k}}$$

Induced surface charge density $E_{\perp} = \sigma/\epsilon_0$:
 $\sigma(x, y) = -\epsilon_0 \left. \frac{\partial V(x, y, z)}{\partial n} \right|_{z=0}$

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Infinite grounded conducting plane: Surface Charge Density



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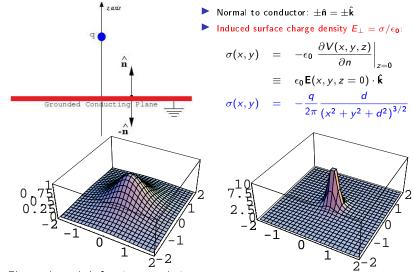


Figure shows $|\sigma|$, for d = 1 and d = 0.1 \implies Maximum induced charge density is right below the point charge

Total induced surface charge: (with $dA = dx dy = s ds d\phi$)

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$$= -\frac{qd}{2\pi} \int_{0}^{\infty} \frac{s \, ds}{(s^2 + d^2)^{3/2}} \int_{0}^{2\pi} d\phi$$
$$= -\frac{qd}{2\pi} \left[-\frac{1}{(s^2 + d^2)^{1/2}} \right]_{s=0}^{s=\infty} (2\pi)$$
$$Q_{\text{induced}} = -q$$

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Electric Field at P(x, y, z) in \mathcal{D} , that we have already calculated:

$$\mathbf{E}(x,y,z) = \frac{1}{4\pi\epsilon_0} \left[q \left(\frac{x\hat{\mathbf{i}} + y\hat{\mathbf{j}} + (z-d)\hat{\mathbf{k}}}{(x^2 + y^2 + (z-d)^2)^{3/2}} \right) + (-q) \left(\frac{x\hat{\mathbf{i}} + y\hat{\mathbf{j}} + (z+d)\hat{\mathbf{k}}}{(x^2 + y^2 + (z+d)^2)^{3/2}} \right) \right]$$

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- ► Electric Field → Induced charges ≡ Electric Field → Image charge:

$$\mathbf{E}_{\text{induced}}(x, y, z) \equiv \mathbf{E}_{\text{image}}(x, y, z) = \frac{(-q)}{4\pi\epsilon_0} \frac{x\hat{\mathbf{i}} + y\hat{\mathbf{j}} + (z+d)\hat{\mathbf{k}}}{(x^2 + y^2 + (z+d)^2)^{3/2}}$$

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Force on q due to conducting plane \equiv Force on q due to Image charge:

$$\begin{array}{lll} \mathsf{F}_{q} &=& q\mathsf{E}_{\mathrm{induced}}(0,0,d) \equiv q\mathsf{E}_{\mathrm{image}}(0,0,d) \\ &=& -\frac{q^{2}\hat{\mathsf{z}}}{4\pi\epsilon_{0}(2d)^{2}} \rightarrow \mathrm{Attractive\ force} \end{array}$$

Electric Field at P(x, y, z) in \mathcal{D} , that we have already calculated:

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*QUESTION: Is there any difference in calculated physical quantities in nonconducting region \mathcal{D} , between those obtained from the *Fictitious System* (charge-image) and those from the *Real System* (charge-conductor)?

Configuration energy of Real System:

Work done by external agent to assemble the charge-conductor system is

$$W_1^{\text{ext}}(\text{Real}) = -\int_{z=\infty}^{z=d} \mathbf{F}_q(z) \cdot d\mathbf{z}$$

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Configuration energy of Fictitious System:

Work done by external agent to assemble the charge-image system is

$$W_2^{\text{ext}}(\text{Fictitious}) = -\frac{q^2}{4\pi\epsilon_0(2d)} = -\frac{q^2}{8\pi\epsilon_0 d!}$$

 \implies It takes only half the amount of energy to assemble the Real System!!

Configuration energy of Real System:

Work done by external agent to assemble the charge-conductor system is

$$W_1^{\text{ext}}(\text{Real}) = -\int_{z=\infty}^{z=d} \mathbf{F}_q(z) \cdot d\mathbf{z} = \int_{\infty}^d \frac{q^2 dz}{4\pi\epsilon_0 (2z)^2} = -\frac{1}{2} \left(\frac{q^2}{8\pi\epsilon_0 d}\right)$$

Configuration energy of Fictitious System:

Work done by external agent to assemble the charge-image system is

$$W_2^{\text{ext}}(\text{Fictitious}) = -\frac{q^2}{4\pi\epsilon_0(2d)} = -\frac{q^2}{8\pi\epsilon_0 d!}$$

 \implies It takes only half the amount of energy to assemble the Real System!!

Intuitive way of understanding this difference is to use the integral formula:

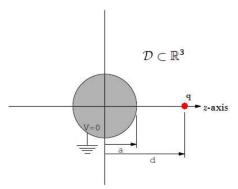
$$U_E(\text{Fictitious}) = \frac{\epsilon_0}{2} \iiint_{\mathbb{R}^3} E^2 dv = 2 \cdot \frac{\epsilon_0}{2} \iiint_{\mathcal{D}} E^2 dv = 2 U_E(\text{Real}).$$

 \Longrightarrow The true domain of integration ${\cal D}$ is only half the domain ${\mathbb R}^3$ for the Fictitious System.

Example

Consider a grounded conducting sphere of radius a and a charge q held at a distance of d from the center. What is the potential in region D outside the conducting sphere?

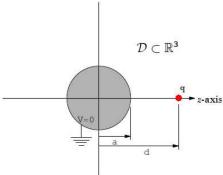
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Potential V(x, y, z) is needed in \mathcal{D}

Example

Consider a grounded conducting sphere of radius *a* and a charge *q* held at a distance of *d* from the center. What is the potential in region \mathcal{D} outside the conducting sphere?



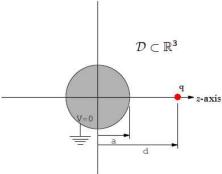
Set up co-ordinate system with z-axis along the line joining the center and q

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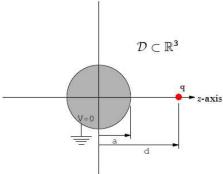
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• Domain: $\mathcal{D} \subset \mathbb{R}^3 = \{\mathbf{r} \mid \mathbf{r} > \mathbf{a}\}$

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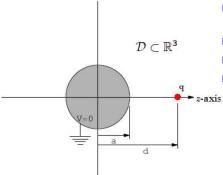
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$$S = \{ \mathbf{r} \mid \mathbf{r} = \mathbf{a} \} \cup S_{\infty}$$

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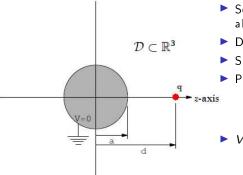
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$$\rho(\mathbf{r}) = q\delta^3 \left(\mathbf{r} - d\hat{\mathbf{k}}\right)$$

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Potential V(x, y, z) is needed in \mathcal{D}

The Real System

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- ► Point charge density:

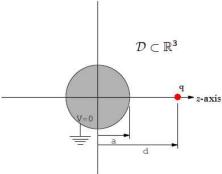
$$\rho(\mathbf{r}) = q\delta^3 \left(\mathbf{r} - d\hat{\mathbf{k}}\right)$$

V(r) satisfies Poisson's Equation:

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Potential V(x, y, z) is needed in \mathcal{D} The Real System

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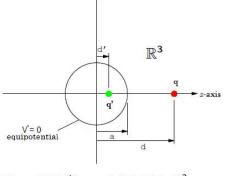
Boundary Condition for Potential:

$$V(\mathbf{S}) = 0, \ \forall \mathbf{S} \in S$$

Replace Real System with Fictitious System: Real charge q, Image charge q' & Equipotential surface $\implies V'(\mathbf{r})$ in \mathbb{R}^3 is identical to $V(\mathbf{r})$ in \mathcal{D} .

Note: You should never put the Image charge in \mathcal{D} where you want to calculate the potential. It should not mater if V' yields the wrong answer outside \mathcal{D} !

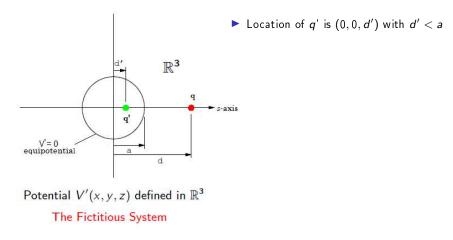
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Potential V'(x, y, z) defined in \mathbb{R}^3 The Fictitious System

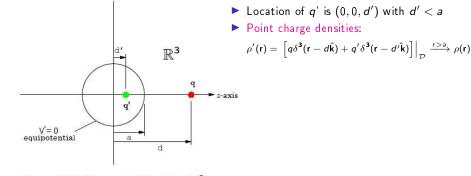
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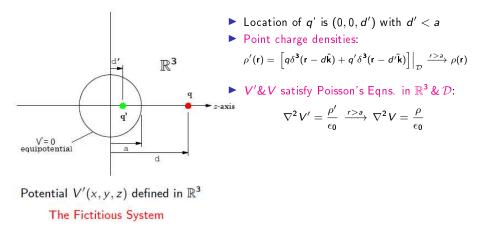
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Potential V'(x, y, z) defined in \mathbb{R}^3 The Fictitious System

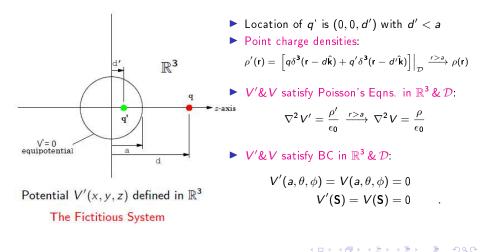
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